## NSN 5961-00-058-6280

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-058-6280

## **Inclosure Material:**

Metal

**Overall Length:** 

0.520 inches

## **Overall Height:**

0.520 inches

## **Overall Diameter:**

1.250 inches

## **Mounting Facility Quantity:**

1

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

## Internal Junction Configuration:

Npn

## Mounting Method:

Threaded stud

## **Features Provided:**

Hermetically sealed case

## Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage, dc with specified circuit between base and emitter and 50.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

6.00 amperes source cutoff current megahertz and 10.00 amperes collector current, dc

#### **Power Rating Per Characteristic:**

150.0 watts collector power dissipation

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

2 pin and 1 threaded stud

#### **Specification Data:**

81349-mil-s-19500/248 government specification

Shelf Life:

NI/o

# NSN 5961-00-058-6280

Transistor - Page 2 of 2

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

